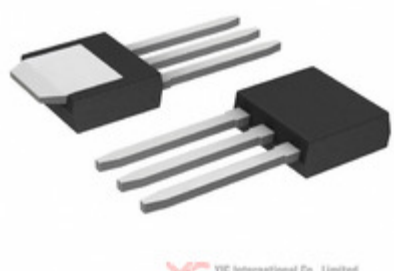


	<p><b>Hersteller-Teilenummer:</b> <a href="#">NTD14N03R-001</a></p>
	<p><b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a></p>
	<p><b>Teil der Beschreibung:</b> MOSFET N-CH 25V 2.5A IPAK</p>
	<p><b>Datenblätter:</b>  <a href="#">NTD14N03R-001.pdf</a></p>
	<p><b>RoHs Status:</b> Enthält Blei / RoHS nicht konform</p>
	<p><b>Lagerzustand:</b> New original, 37363 pcs Stock Available.</p>
	<p><b>Liefern von:</b> Hong Kong</p>
	<p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">NTD14N03R-001</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET N-CH 25V 2.5A IPAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	37363 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	1.04W (Ta), 20.8W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	25V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	2.5A (Ta)
Rds On (Max) @ Id, Vgs	95 mOhm @ 5A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	1.8nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	115pF @ 20V
Verpackung	Tube



















































NTD14N03R-001 ist neu im Original, Suche NTD14N03R-001 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD14N03R-001 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD14N03R-001: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>NTD14N03</b> ON NTD14N03 ON</p>	 <p><b>NTD12N10T4</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12A DPAK</p>	 <p><b>NTD14N03R</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 2.5A DPAK</p>	 <p><b>NTD14N03RT4</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 2.5A DPAK</p>
 <p><b>NTD14N03RG</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 2.5A DPAK</p>	 <p><b>NTD14N03R-1</b> O NTD14N03R-1 O</p>	 <p><b>NTD14N03RT4G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 2.5A DPAK</p>	 <p><b>NTD14N03R-1G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 2.5A IPAK</p>

### heiße Teile

Mehr

 NTD110N02	 NTD110N02R	 NTD110N02R-001	 NTD110N02R-001G	 NTD110N02RG
 NTD110N02RT4G	 NTD12N10-001	 NTD12N10-1G	 NTD12N10G	 NTD12N10T4
 NTD12N10T4G	 NTD14N03	 NTD14N03G	 NTD14N03R	 NTD14N03R-1
 NTD14N03R-1G	 NTD14N03RG	 NTD14N03RT4	 NTD14N03RT4G	 NTD14N03RTCG
 NTD14N03T4G	 NTD15N06	 NTD15N06L	 NTD15N06LG	 NTD15N06LT4
 NTD15N06LT4G	 NTD15N06T4	 NTD15N06T4G	 NTD15N06VLT4	 NTD15N07
 NTD15N10	 NTD18N06-001	 NTD18N06-1G	 NTD18N06G	 NTD18N06L
 NTD18N06L-1G	 NTD18N06LG	 NTD18N06LT4G	 NTD18N06T4G	 NTD20N03
 NTD20N03G	 NTD20N03HL	 NTD20N03L27	 NTD20N03L27G	 NTD20N03L27T
 NTD20N03L27T4	 NTD20N03L27T4G	 NTD20N03RT4G	 NTD20N06	 NTD20N06-001

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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